Docket No.: 3536 C02 Serial No.: 09/775,295 INFORMATION OIP **DISCLOSURE** Applicant(s): JAMES CARDUCCI, ET AL. CITATION FORM FOR PATENT APPLICATION MAY 1 7 2001 (FORM PTO - 1449) Filting Date: 01-31-01 Group: & PADEMARK OFF U. S. PATENTS Initials Patent No Issue Date Name € S 4,438,723 03-27-84 CANNELLA ET AL. 4,440,107 04-03-84 DOEHLER ET AL. 4,483,737 11-20-84 **MANTEI** 4,810,935 03-07-89 **BOSWELL** 4,842,707 **KINOSHITA** 06-27-89 4,990,229 02-05-91 CAMPBELL ET AL. 4,993,361 02-19-91 **UNVALA** 5,091,049 02-25-92 CAMPBELL ET AL. 5,122,251/ 06-16-92 CAMPBELL ET AL. 5,160,398 11-03-92 YANAGIDA 5,178,739 01-12-93 BARNES ET AL. 5,224,441 07-06-93 FELTS ET AL. 5,346,579 09-13-94 COOK ET AL. FOREIGN PATENT DOCUMENTS Initials Document Number Date Country Name EP 0 173 583 05.03.86 KIM KUYNGSHIK ET AL. **EUROPE** EP 0 651 425/ ROBERT CHAPMAN 03.05.95 **EUROPE** EP 0 786 794 03.07.97 PETER LOEWENHARDT ET AL. **EUROPE** N/A 7-22389 24.01.95 **JAPAN** YUTAKA KAKCHI ET AL. NDA4 Initials Other Documents (Title, Author, Date, Pages, Etc., if known) Quick, A.K., Chen, R.T.S., and Hershkowitz, N., "Etch rate and plasma density radial uniformity measurements in a cusped field helicon plasma etcher," J. Vac. Sci. Technol., Vol. 14, No. 3, May/June 1996, pp. 1041-1045. Date Considered: Examiner's Signature: Initial if reference was considered, whether or not citation with MPEP. Mark through citation if not considered. Include a copy of this citation form with your next correspondence to the Applicant(s).

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INFORMATION **DISCLOSURE** CITATION FORM FORTHAD PATENT APPLICATION

Docket No.:

3536 C02

Serial No.:

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Applicant(s):

JAMES CARDUCCI, ET AL.

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Page No. 1 Of 1 MAY 1 4 2001 **INFORMATION** 3536 C02 09/775,295 Docket No.: Serial No.: **DISCLOSURE** CITATION FORM FOR TRADE JAMES CARDUCCI, ET AL. Applicant(s): PATENT APPLICATION Group: (FORM PTO - 1449) 01-31-01 Filing Date: U.S. PATENTS Initials Patent No Issue Date Name Class Subclass Filing Date RECEIVED
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Date Considered:

George Goudrean

Examiner's Signature: